

Supplementary Information

FAPbBr₃ perovskite solar cells with V_{OC} over 1.5 V by controlled crystal growth using a tetramethylenesulfoxide

*Youhei Numata^{*a} Naoyuki Shibayama^b and Tsutom Miyasaka^{*b}*

^a Research Center for Advanced Science and Technology (RCAST), The University of Tokyo, 4-6-1 Komaba, Meguro-ku, Tokyo 153-8904 Japan

^b Department of Engineering, Toin University of Yokohama, 1614 Kurgane-cho, Aoba, Yokohama, Kanagawa 225-8503 Japan.

Table S1. Photovoltaic parameters of FAPbBr₃ PSCs with different TMSO concentrations in DMSO solvent. Device architecture: FTO/TiO₂ CL/TiO₂ meso/FAPbBr₃/spiro/Au.

TMSO content in DMSO (%)	scan direction	J_{SC} (mA/cm ²)	V_{OC} (V)	FF	PCE (%)
0	forward	4.87 ± 0.16	1.32 ± 0.05	0.49 ± 0.02	3.15 ± 0.18
	reverse	4.85 ± 0.10	1.31 ± 0.06	0.54 ± 0.01	3.45 ± 0.19
5	forward	6.01 ± 0.14	1.30 ± 0.03	0.49 ± 0.02	3.80 ± 0.26
	reverse	5.78 ± 0.06	1.32 ± 0.04	0.52 ± 0.01	3.99 ± 0.16
10	forward	6.08 ± 0.14	1.30 ± 0.01	0.49 ± 0.03	3.91 ± 0.32
	reverse	5.71 ± 0.10	1.35 ± 0.01	0.56 ± 0.03	4.28 ± 0.26
20	forward	6.31 ± 0.11	1.28 ± 0.02	0.51 ± 0.01	4.11 ± 0.20
	reverse	6.04 ± 0.11	1.31 ± 0.02	0.54 ± 0.01	4.25 ± 0.19

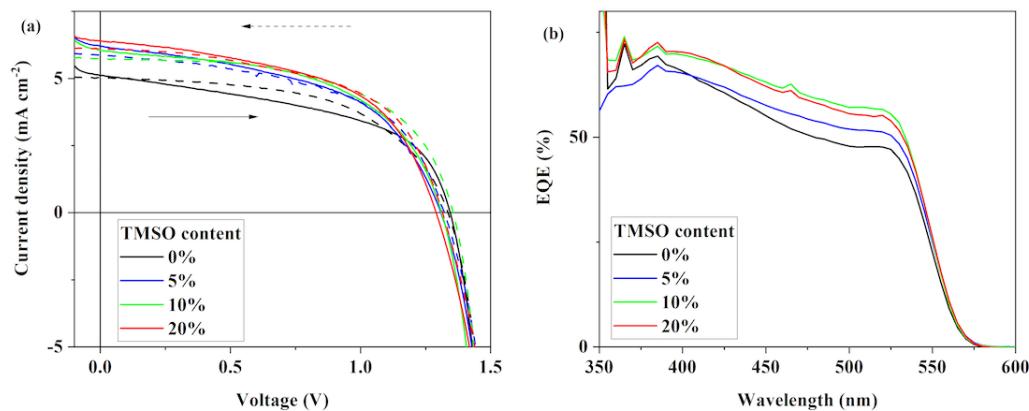


Fig. S1 (a) J - V curves and (b) EQE spectra of FAPbBr₃ PSCs with different TMSO content. Device architecture: FTO/TiO₂ CL/TiO₂ meso/FAPbBr₃/spiro/Au.

Note. Above PSCs were not conducted Li-treatment of TiO₂ mesoporous layer and insertion of PMMA blocking layer.

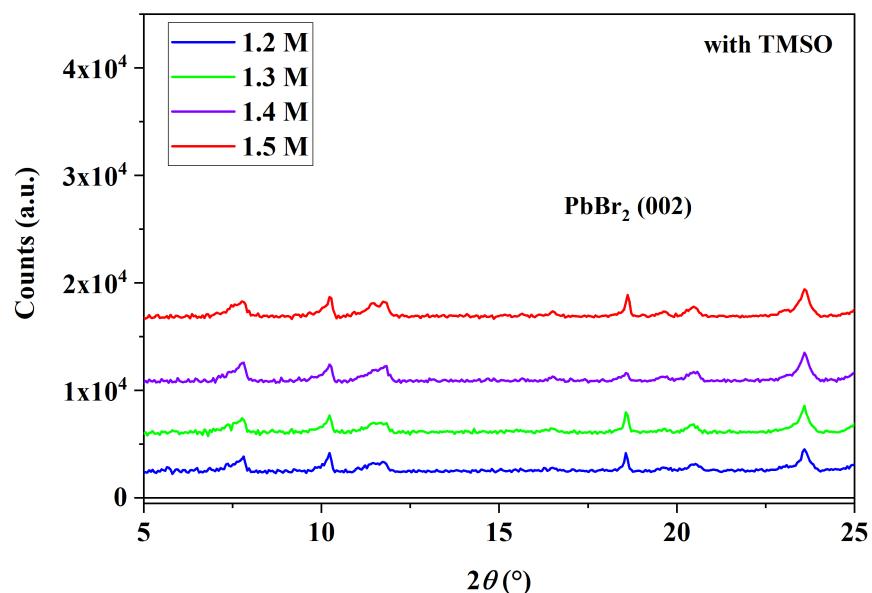


Fig. S2 XRD chart of PbBr_2 -TMSO films prepared on Li-treated TiO_2 mesoporous layer; vertical axis was enlarged 100 times from **Fig. 1a**.

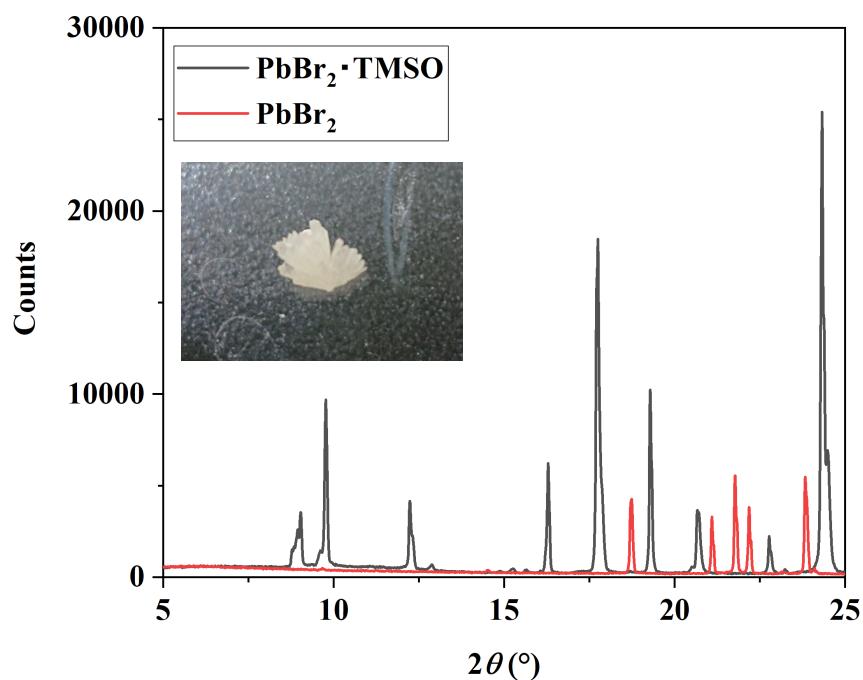


Fig. S3 XRD chart of ground $\text{PbBr}_2 \cdot \text{TMSO}$ single crystal and PbBr_2 powder. Inset: photograph of $\text{PbBr}_2 \cdot \text{TMSO}$ single crystals.

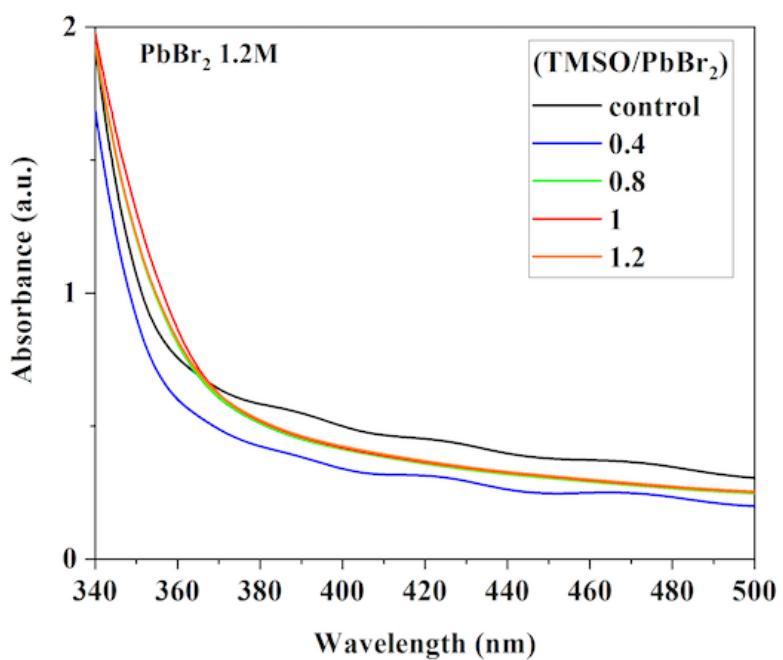


Fig. S4 UV spectra of PbBr_2 films with different concentration of TMSO in DMSO solvent. The PbBr_2 films were prepared on a Li-treated TiO_2 mesoporous film.

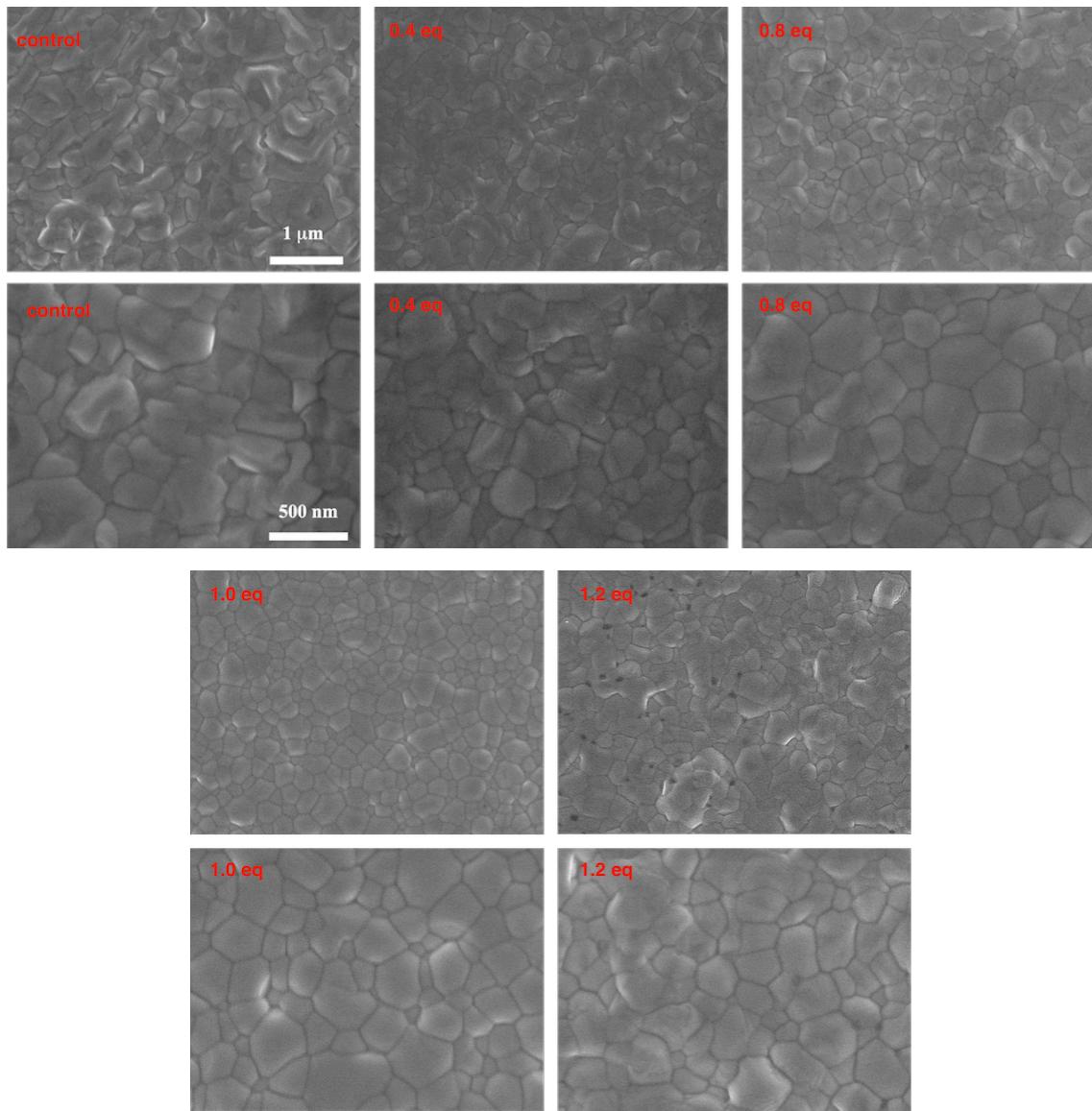


Fig. S5 surface SEM images of FAPbBr₃ films with different concentration of TMSO.

The FAPbBr₃ films were prepared on a Li-treated TiO₂ mesoporous film.

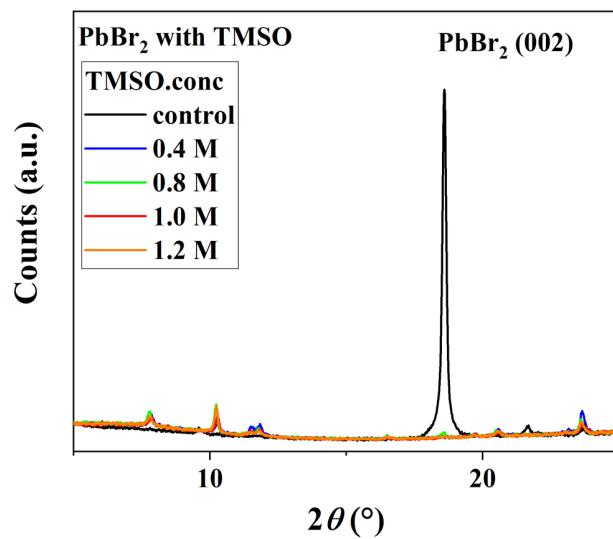


Fig. S6 XRD chart of PbBr₂ films with different concentration of TMSO in DMSO solvent.

Table S2. Photovoltaic parameters of FAPbBr₃ PSCs with and w/o TMSO

TMSO	PbBr ₂ conc. (M)	Scan direction	<i>J</i> _{SC} (mA cm ⁻²)	<i>V</i> _{OC} (V)	FF	<i>η</i> (%)
w/o	1.0	forward	3.49 ± 0.46	1.42 ± 0.02	0.44 ± 0.04	2.19 ± 0.44
		reverse	3.27 ± 0.45	1.41 ± 0.05	0.43 ± 0.02	1.98 ± 0.37
	1.2	forward	5.55 ± 0.15	1.38 ± 0.02	0.60 ± 0.03	4.59 ± 0.28
		reverse	5.36 ± 0.14	1.41 ± 0.02	0.56 ± 0.04	4.21 ± 0.36
	1.3	forward	5.56 ± 0.34	1.35 ± 0.02	0.61 ± 0.04	4.63 ± 0.49
		reverse	5.29 ± 0.34	1.36 ± 0.02	0.66 ± 0.04	4.73 ± 0.35
	1.4	forward	5.74 ± 0.38	1.35 ± 0.02	0.57 ± 0.04	4.48 ± 0.57
		reverse	5.35 ± 0.28	1.34 ± 0.04	0.68 ± 0.08	4.86 ± 0.72
with	1.2	forward	6.41 ± 0.13	1.45 ± 0.02	0.59 ± 0.03	5.50 ± 0.38
		reverse	6.12 ± 0.14	1.47 ± 0.02	0.61 ± 0.04	5.50 ± 0.46
	1.3	forward	6.53 ± 0.23	1.43 ± 0.03	0.60 ± 0.06	5.62 ± 0.73
		reverse	6.17 ± 0.31	1.47 ± 0.02	0.66 ± 0.05	5.95 ± 0.58
	1.4	forward	7.05 ± 0.13	1.13 ± 0.07	0.48 ± 0.08	3.81 ± 0.82
		reverse	6.53 ± 0.36	1.24 ± 0.08	0.59 ± 0.04	4.72 ± 0.45
	1.5	forward	6.93 ± 0.46	1.08 ± 0.11	0.48 ± 0.09	3.60 ± 1.02
		reverse	6.47 ± 0.56	1.18 ± 0.07	0.59 ± 0.07	4.49 ± 0.73

Cell area: 0.25 cm² (5 × 5 mm²), aperture area was defined with black metal mask. The parameters are average values of 12~18 cells

FAPbBr₃ (with TMSO)

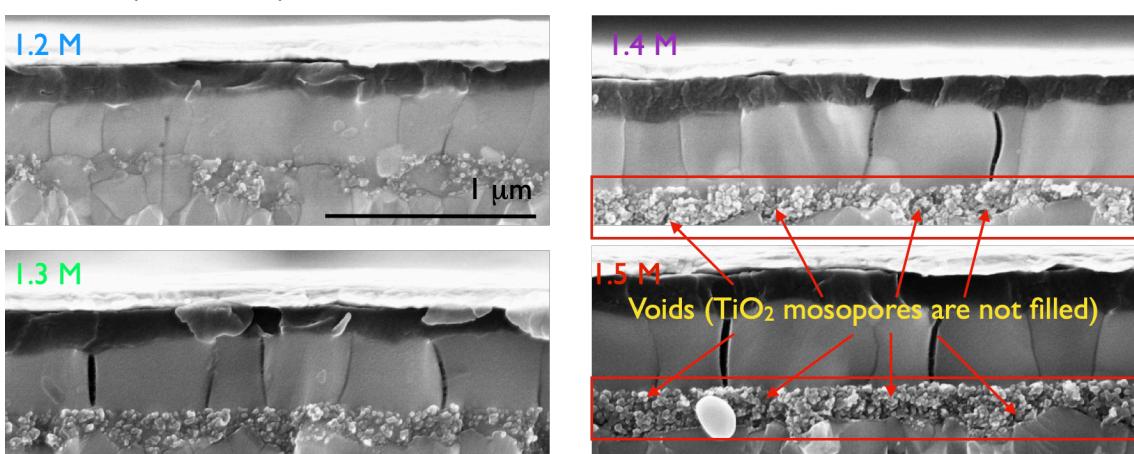


Fig. S7 Cross-sectional images of FAPbBr₃ (with TMSO) cells.

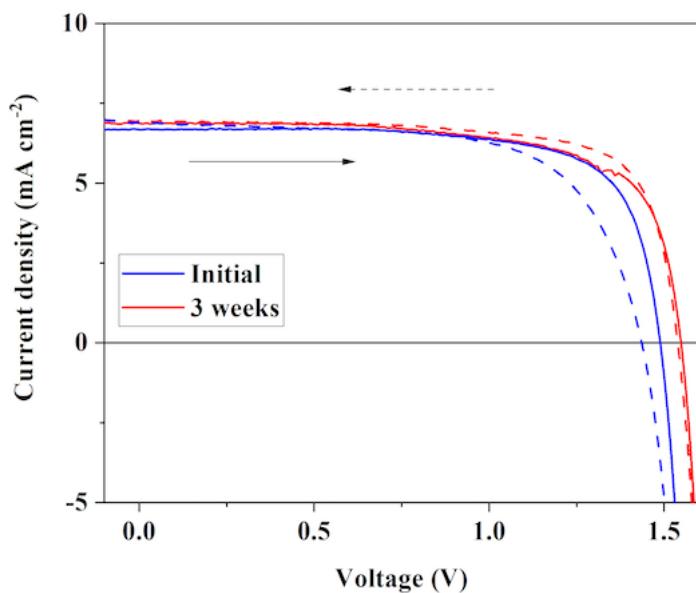


Fig. S8 Aging effect of FAPbBr₃ PSC based on a 1.3 M PbBr₂–TMSO precursor film stored under dark and dry condition for 3 weeks.

Table S3 Summary of reported high-voltage Br-rich 3-D perovskite-based solar cells with V_{OC} over 1.4 V

Device architecture	V_{OC} (V)	J_{SC} (mA/cm ²)	FF	η (%)	method	Ref.
MAPbBr₃						
FTO/c-TiO ₂ /MAPbBr ₃ / Carbon	1.535	7.10	0.70	7.63	one-step	1
FTO/bl-TiO ₂ /m-TiO ₂ / MAPbBr ₃ /PIF8-TAA/Au	1.40	6.1	0.79	6.7	one-step	2
FTO/NiOx/MoOx/ MAPbBr ₃ /ZrO/PC ₆₁ BM/Al	1.653	7.72	0.79	10.08	one-step	3
FTO/c-TiO ₂ /m-TiO ₂ / MAPbBr ₃ /PTAA/Au	1.4	6.4	74	6.6	two-step	4
FAPbBr₃						
ITO/P3CT/FAPbBr ₃ / PCBM/C ₆₀ /BCP/Cu	1.49	8.98	66.74	8.93	two-step	5
FTO/SnO ₂ /FAPbBr ₃ /spiro/Au	1.552	8.94	0.76	10.61	two-step	6
FTO/c-TiO ₂ /Li-m-TiO ₂ / FAPbBr ₃ /spiro/Au	1.53	7.3	0.71	8.2	two-step	7
FTO/c-TiO ₂ /m-TiO ₂ / FAPbBr ₃ /spiro/Au	1.42	6.8	72	7.0	two-step	8
FTO/c-TiO ₂ /m-TiO ₂ /FAPbBr ₃ / SO7/Au	1.50	6.9	69	7.1	two-step	9
FTO/NiO/FAPbBr ₃ /Mg-ZnO/ PCBM/BCP/Ag	1.44	8.92	0.71	9.06	one-step	10
FTO/TiO ₂ /Li-m-TiO ₂ /FAPbBr ₃ /PMMA/spiro/Au cell area: 0.25 mm ²	1.53	6.96	0.74	7.88	two-step	This work
CsPbBr₃						
FTO/SnO ₂ /GQDs/ CsPbBr ₃ /Carbon	1.522	7.91	78.4	9.51	two-step	11
FTO/c-TiO ₂ /m-TiO ₂ / Sm-CsPbBr ₃ /Carbon	1.594	7.48	85.1	10.14	two-step	12
FTO/c-TiO ₂ /m-TiO ₂ / CsPbBr ₃ /Carbon	1.584	7.42	82.11	9.65	two-step	13
FTO/c-TiO ₂ /m-TiO ₂ / CsPbBr ₃ /Carbon	1.432	7.86	81	6.78	two-step	14
FTO/c-TiO ₂ /Li-m-TiO ₂ / CsPbBr ₃ /spiro/Au	1.45	5.97	70	6.19	two-step	15
FTO/c-TiO ₂ /m-TiO ₂ / CsPbBr ₃ /spiro/Au	1.43	8.85	0.62	7.86	two-step	16
FTO/c-TiO ₂ /m-TiO ₂ / m-ZrO ₂ /CsPbBr ₃ /Carbon	1.44	7.75	73.52	8.19	two-step	17
FTO/c-TiO ₂ /m-TiO ₂ / CsPbBr ₃ /P3HT-ZnPc/ Carbon	1.578	7.652	83.06	10.03	two-step	18
FTO/ZnO/ CsPbBr ₃ -CsPb ₂ Br ₅ /spiro/Au	1.43	6.17	77.2	6.31	two-step	19
ITO/c-TiO ₂ /CsPbBr ₃ / Carbon	1.51	7.3	0.75	8.3	mist-CVD	20

FTO/c-TiO ₂ /m-TiO ₂ /CsPbBr ₃ -L-lysine/Carbon	1.565	7.64	81.0	9.68	two-step	21
FTO/c-TiO ₂ /Sb-TiO ₂ /CsPbBr ₃ /Carbon	1.654	6.70	80.4	8.91	two-step	22
FTO/c-TiO ₂ /m-TiO ₂ /CsPb _{0.97} Sr _{0.03} Br ₃ /Carbon	1.54	7.71	81.1	9.63	two-step	23
FTO/c-TiO ₂ /m-TiO ₂ /CsPb _{0.97} Tb _{0.03} Br ₃ /SnS:ZnS/NiOx/Carbon	1.57	8.21	79.6	10.26	two-step	24
FTO/c-TiO ₂ /m-TiO ₂ /CsPbBr ₃ /MnS/Carbon	1.52	8.28	0.83	10.45	two-step	25
FTO/c-TiO ₂ /m-TiO ₂ /CsPbBr ₃ /Carbon-MWCNT	1.431	6.84	0.78	7.62	two-step	26
FTO/c-TiO ₂ /m-TiO ₂ /CsPbBr ₃ /[BMMIM]Cl/Carbon	1.61	7.45	83	9.92	two-step	27
FTO/c-TiO ₂ /m-TiO ₂ /CsPbBr ₃ /Carbon	1.458	8.12	82.1	9.72	two-step	28
ITO/NiMgOx/PVP/CsPbBr ₃ :AVAB/CdSe QDs/ZnO/Al	1.73	3.5	N/A	N/A	two-step	29
FTO/L-TiO ₂ :MoSe ₂ /CsPbBr ₃ /Carbon	1.615	7.88	78.7	10.02	two-step	30
FTO/c-TiO ₂ /m-TiO ₂ /GQDs/CsPbBr ₃ /CISZ-QD/Carbon	1.522	7.35	84.3	9.43	two-step	31
FTO/N-TiO ₂ -NRA/CsPbBr ₃ /Carbon	1.58	6.55	81.96	8.50	two-step	32
FTO/TiO ₂ /CsPbBr ₃ QDs/PTB7/MoO ₃ /Ag	1.61	3.5	75.95	4.28	QD spin-coat	33
CsPbI₂Br						
ITO/SnO ₂ /SnOx/CsPbI ₂ Br/poly(DTSTPD-r-BThTPD)/Au	1.41	14.25	0.77	15.53	one-step	34
ITO/SnO ₂ /SnOx/CsPbI ₂ Br/PDTDT/Au	1.42	15.02	81.29	17.36	one-step	35

References

- Y. Liang, Y. Wang, C. Mu, S. Wang, X. Wang, D. Xu and L. Sun, *Adv. Energy Mater.*, 2018, **8**, 1701159.
- S. Ryu, J. H. Noh, N. J. Jeon, Y. Chan Kim, W. S. Yang, J. Seo and S. Il Seok, *Energy Environ. Sci.*, 2014, **7**, 2614–2618.
- X. Hu, X. F. Jiang, X. Xing, L. Nian, X. Liu, R. Huang, K. Wang, H. L. Yip and G. Zhou, *Sol. RRL*, 2018, **2**, 1800083.
- M. Kulbak, S. Gupta, N. Kedem, I. Levine, T. Bendikov, G. Hodes and D. Cahen, *J. Phys. Chem. Lett.*, 2016, **7**, 167–172.
- S. Li, C. Deng, L. Tao, Z. Lu, W. Zhang and W. Song, *J. Phys. Chem. C*, 2021, **125**, 12551–12559.

- 6 Y. Zhang, Y. Liang, Y. Wang, F. Guo, L. Sun and D. Xu, *ACS Energy Lett.*,
2018, **3**, 1808–1814.
- 7 N. Arora, M. I. Dar, M. Abdi-Jalebi, F. Giordano, N. Pellet, G. Jacopin, R. H.
Friend, S. M. Zakeeruddin and M. Grätzel, *Nano Lett.*, 2016, **16**, 7155–7162.
- 8 N. Arora, M. I. Dar, M. Hezam, W. Tress, G. Jacopin, T. Moehl, P. Gao, A. S.
Aldwayyan, B. Deveaud, M. Grätzel and M. K. Nazeeruddin, *Adv. Funct. Mater.*,
2016, **26**, 2846–2854.
- 9 N. Arora, S. Orlandi, M. I. Dar, S. Aghazada, G. Jacopin, M. Cavazzini, E.
Mosconi, P. Gratia, F. De Angelis, G. Pozzi, M. Graetzel and M. K. Nazeeruddin,
ACS Energy Lett., 2016, **1**, 107–112.
- 10 C. Hu, S. B. Shivarudraiah, H. H. Y. Sung, I. D. Williams, J. E. Halpert and S.
Yang, *Sol. RRL*, 2021, **5**, 2000712.
- 11 Y. Zhao, J. Zhu, B. He and Q. Tang, *ACS Appl. Mater. Interfaces*, 2021, **13**,
11058–11066.
- 12 J. Duan, Y. Zhao, X. Yang, Y. Wang, B. He and Q. Tang, *Adv. Energy Mater.*,
2018, **8**, 1802346.
- 13 J. Zhu, B. He, Z. Gong, Y. Ding, W. Zhang, X. Li, Z. Zong, H. Chen and Q.
Tang, *ChemSusChem*, 2020, 1834–1843.
- 14 J. Ding, Y. Zhao, J. Duan, B. He and Q. Tang, *ChemSusChem*, 2018, **11**,
1432–1437.
- 15 P. Yadav, M. H. Alotaibi, N. Arora, M. I. Dar, S. M. Zakeeruddin and M. Grätzel,
Adv. Funct. Mater., 2018, **28**, 1706073.
- 16 X. Wang, S. Abbasi, D. Zhang, J. Wang, Y. Wang, Z. Cheng, H. Liu and W.
Shen, *ACS Appl. Mater. Interfaces*, 2020, **12**, 50455–50463.
- 17 I. Poli, J. Baker, J. McGettrick, F. De Rossi, S. Eslava, T. Watson and P. J.
Cameron, *J. Mater. Chem. A*, 2018, **6**, 18677–18686.
- 18 Y. Liu, B. He, J. Duan, Y. Zhao, Y. Ding, M. Tang, H. Chen and Q. Tang, *J.
Mater. Chem. A*, 2019, **7**, 12635–12644.
- 19 X. Zhang, Z. Jin, J. Zhang, D. Bai, H. Bian, K. Wang, J. Sun, Q. Wang and S. F.
Liu, *ACS Appl. Mater. Interfaces*, 2018, **10**, 7145–7154.
- 20 Y. Haruta, T. Ikenoue, M. Miyake and T. Hirato, *ACS Appl. Energy Mater.*, 2020,
3, 11523–11528.

- 21 W. Zhang, X. Liu, B. He, J. Zhu, X. Li, K. Shen, H. Chen, Y. Duan and Q. Tang, *ACS Appl. Mater. Interfaces*, 2020, **12**, 36092–36101.
- 22 Y. Xu, J. Duan, X. Yang, J. Du, Y. Wang, Y. Duan and Q. Tang, *J. Mater. Chem. A*, 2020, **8**, 11859–11866.
- 23 Y. Zhao, Y. Wang, J. Duan, X. Yang and Q. Tang, *J. Mater. Chem. A*, 2019, **7**, 6877–6882.
- 24 H. Yuan, Y. Zhao, J. Duan, Y. Wang, X. Yang and Q. Tang, *J. Mater. Chem. A*, 2018, **6**, 24324–24329.
- 25 X. Li, Y. Tan, H. Lai, S. Li, Y. Chen, S. Li, P. Xu and J. Yang, *ACS Appl. Mater. Interfaces*, 2019, **11**, 29746–29752.
- 26 G. Liao, Y. Zhao, J. Duan, H. Yuan, Y. Wang, X. Yang, B. He and Q. Tang, *Dalt. Trans.*, 2018, **47**, 15283–15287.
- 27 W. Zhang, X. Liu, B. He, Z. Gong, J. Zhu, Y. Ding, H. Chen and Q. Tang, *ACS Appl. Mater. Interfaces*, 2020, **12**, 4540–4548.
- 28 J. Duan, Y. Zhao, B. He and Q. Tang, *Angew. Chemie - Int. Ed.*, 2018, **57**, 3787–3791.
- 29 D. Zhou, J. Huang, H. Yan, J. Zhang, L. Lu, P. Xu and G. Li, *ACS Appl. Mater. Interfaces*, 2020, **12**, 50527–50533.
- 30 Q. Zhou, J. Du, J. Duan, Y. Wang, X. Yang, Y. Duan and Q. Tang, *J. Mater. Chem. A*, 2020, **8**, 7784–7791.
- 31 J. Duan, T. Hu, Y. Zhao, B. He and Q. Tang, *Angew. Chemie - Int. Ed.*, 2018, **57**, 5746–5749.
- 32 M. Wang, J. Duan, J. Du, X. Yang, Y. Duan, T. Zhang and Q. Tang, *ACS Appl. Mater. Interfaces*, 2021, **10**, 12091–12098.
- 33 X. Zhang, Y. Qian, X. Ling, Y. Wang, Y. Zhang, J. Shi, Y. Shi, J. Yuan and W. Ma, *ACS Appl. Mater. Interfaces*, 2020, **12**, 27307–27315.
- 34 Z. Guo, A. K. Jena, I. Takei, G. M. Kim, M. A. Kamarudin, Y. Sanehira, A. Ishii, Y. Numata, S. Hayase and T. Miyasaka, *J. Am. Chem. Soc.*, 2020, **142**, 9725–9734.
- 35 Z. Guo, A. K. Jena, I. Takei, M. Ikegami, A. Ishii, Y. Numata, N. Shibayama and T. Miyasaka, *Adv. Funct. Mater.*, 2021, **31**, 2103614.